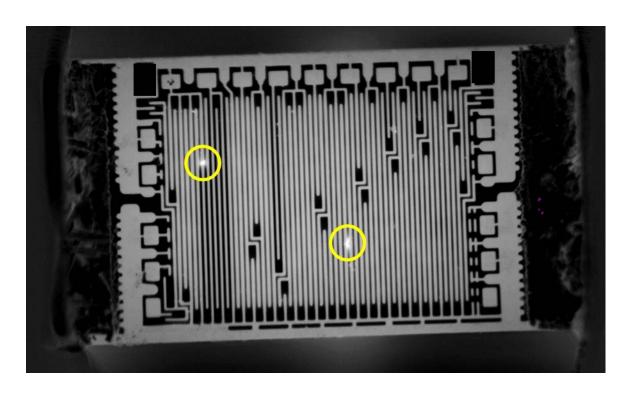
A Screening Method Using Pulsed-Power Combined with Infrared Imaging to Detect Pattern Defects in Bulk Metal Foil or Thin Film Resistors



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Acronyms & Abbreviations

Al-N Aluminum Nitride

DPA Destructive Physical Analysis

FA Failure Analysis

InSb Indium Antimonide

NASA National Aeronautics and Space Administration

NEPP NASA Electronic Parts & Packaging (NEPP) Program

NiCr Nichrome

ppm Parts Per Million

PWB Printed Wiring Board

SEM Scanning Electron Microscope

SMT Surface Mount Technology

SSAI Science Systems and Applications Inc.

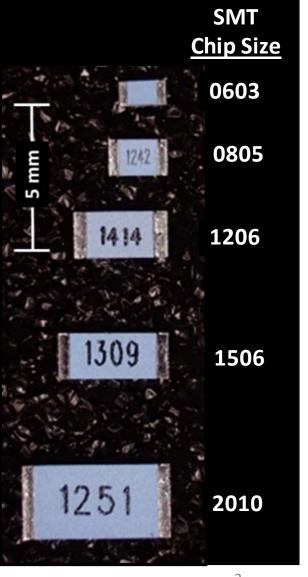
STOL Short Time Over Load

TCR Temperature Coefficient of Resistance

Foil Resistors Have Many Favorable Attributes



Attribute	
Package Configurations	Surface Mount Technology (SMT); Through Hole
Resistance Values	Custom Values; 5Ω to 125kΩ (standard SMT)
Resistance Tolerance	± 0.01% (± 100 ppm)
Temperature Coefficient of Resistance (TCR)	< ± 1 ppm/°C from -55°C to +125°C
Load Life Stability	± 0.03% (± 300ppm) after 2k hour life test @ 1x rated power @ 70°C

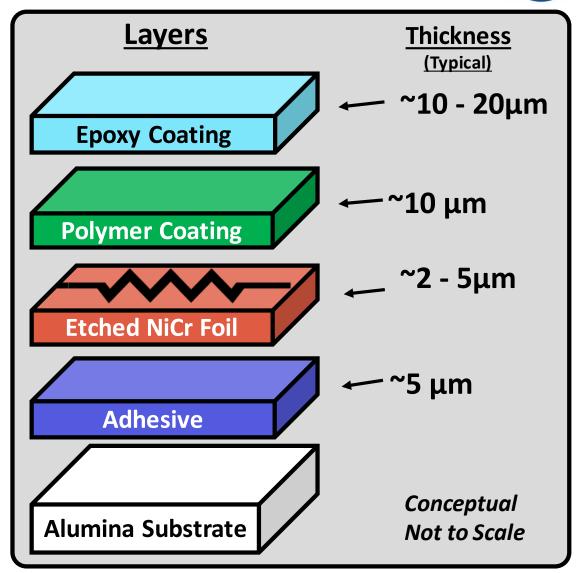


Basic Construction of a SMT Foil Resistor





- Resistor element is made from foil sheets of NiCr-based alloys
- Resistor gridline patterns are created by photolithography and electrochemical etching
- Resistor foil is adhesively-bonded to an alumina substrate
- Precise resistance values achieved by laser or mechanical cutting of combinations of "trim tabs" connected in parallel with resistor pattern segments of different values
- Various resistor termination options exist
- Polymeric and epoxy coatings protect the resistor element



Foil Resistor Gridline Patterns

$$R = \frac{\rho * L}{A}$$

 $R = Resistance (\Omega)$

 ρ = Resistivity of Foil

L = Length of Resistor Element

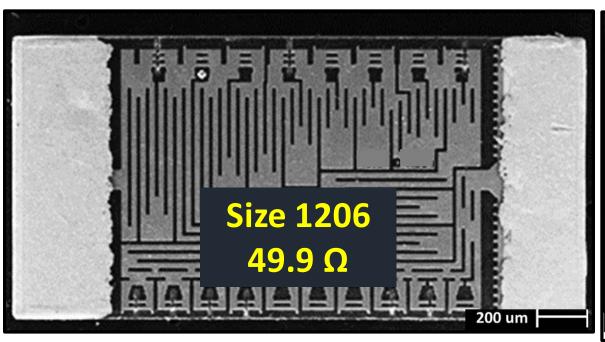
A = Cross Sectional Area of Gridline

(i.e., thickness * width)



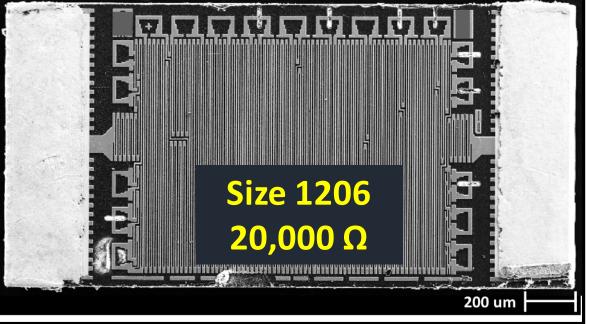
Low Resistance Values

- Wider Foil Gridlines (e.g.,~ > 10 μm)
- 2. Thicker Foil (e.g., ~ 5 μm)
- 3. Shorter Path Lengths



High Resistance Values

- 1. Narrower Foil Gridlines (e.g.,~ < 10 μm)
- 2. Thinner Foil (e.g., $\sim 2 \mu m$)
- 3. Longer Path Lengths



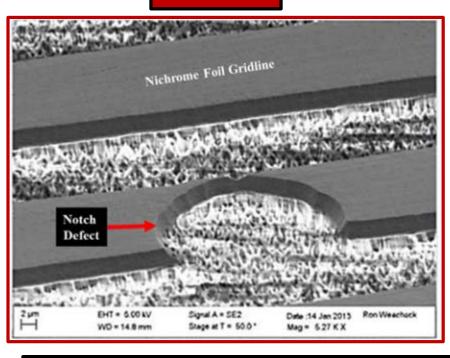
Foil Resistors Are Sometimes Produced with Localized Constriction Defects in the Gridline Pattern

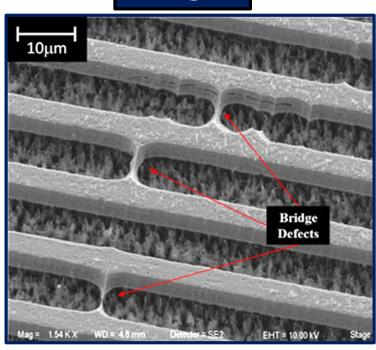


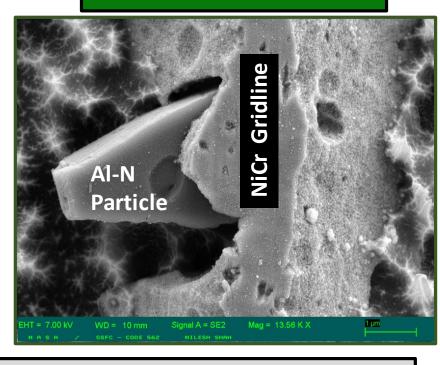
Notches

Bridges

Embedded Particles







- 1. Constriction defects contribute directly to the final resistance value (e.g., bridges provide parallel resistor pathway).
- 2. Constriction defects are at risk of breaking due to thermomechanical fatigue fracture especially during power cycling
 - 1. Constrictions carry higher current density and develop localized 'hot spots' due to Joule heating
 - 2. Hot spots produce locally greater expansion of the NiCr foil
- 3. If a constriction defect fractures, then a positive resistance shift, including open circuit, will occur.

Standard Screening Tests are Not 100% Effective at Detecting Constriction Defects



Despite Performing These Screening Tests,
Foil Resistors with Significant Constriction Defects are Still Occasionally Received

Test Method	Test Conditions	Rejection Criteria
Pre-Encapsulation Optical Microscopy	30x to 60x Magnification	Notches > 75% nominal line width Bridges < 10% smallest line width
Short Time Overload (STOL)	6.25x Rated Power For 5 Seconds	ΔR > 0.02%
Power Conditioning	1x to 1.5x Rated Power @ Max Operating Temp For 100 Hours	ΔR > 0.03%

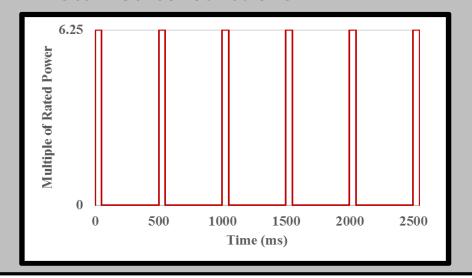
Hot Spots! A New Screening Method to Detect Localized Constrictions



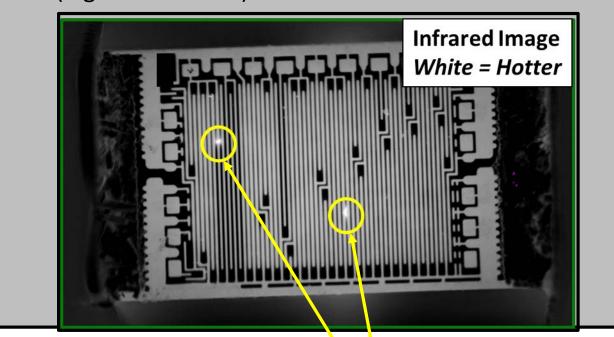
Pulsed-Power Combined with High Resolution Infrared Imaging

1. Apply pulsed-power to resistor

- 6.25x rated power ← same as STOL
- 50 ms, 10% duty cycle
- 1 or more pulses
- These conditions confine heating to the localized constrictions



2. Examine resistor with high resolution infrared camera (e.g. FLIR SC8300)



- 3. Reject resistors with "hot spots"
 - Hot spots are indicative of constriction defects (e.g., notches, bridges, embedded particles)

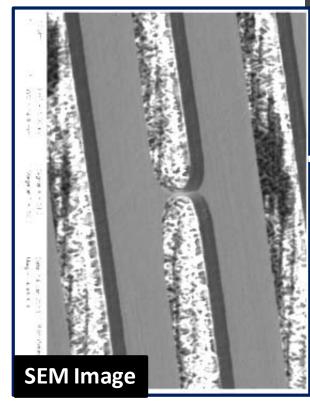
Demonstration of New Screening Method *Using DPA Sample with Bridge and Notch Defects*

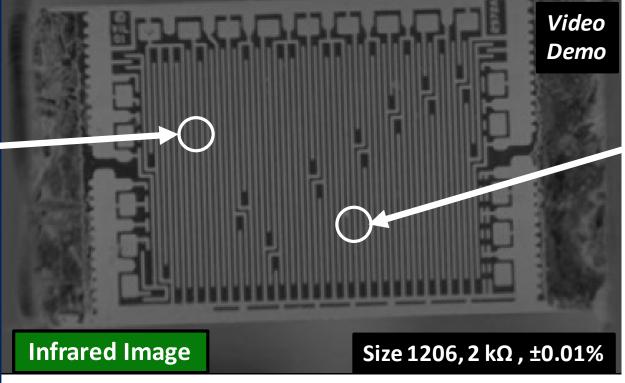


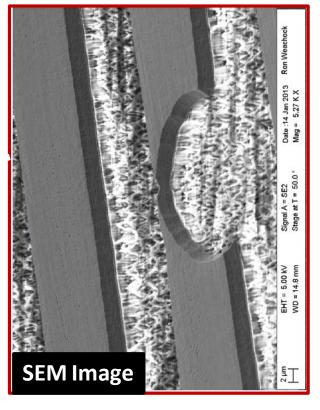
Bridge Defect

Pulsed-Power 6.25x Rated Power 50ms On / 150ms Off

Notch Defect







These Protective Coatings are <u>"See Through"</u> for Infrared Wavelengths of 3µm to 5µm Even With <u>No Power Applied</u> to the Resistor

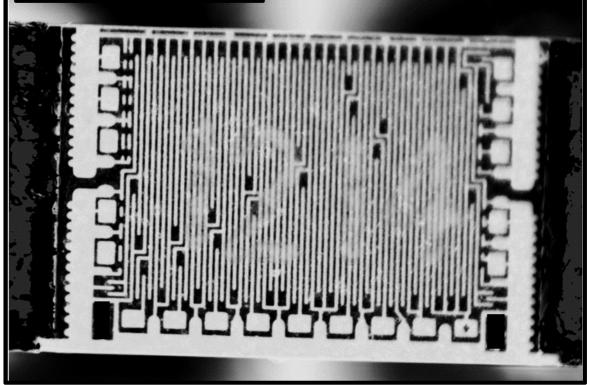


Enables <u>Post-Procurement</u> Screening of SMT Foil Resistors

Optical Image

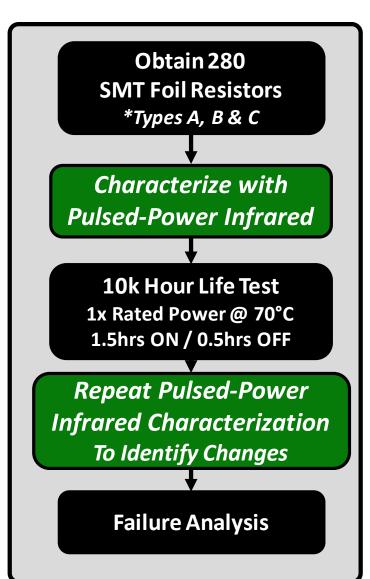


Infrared Image



Evaluation of New Screening Method





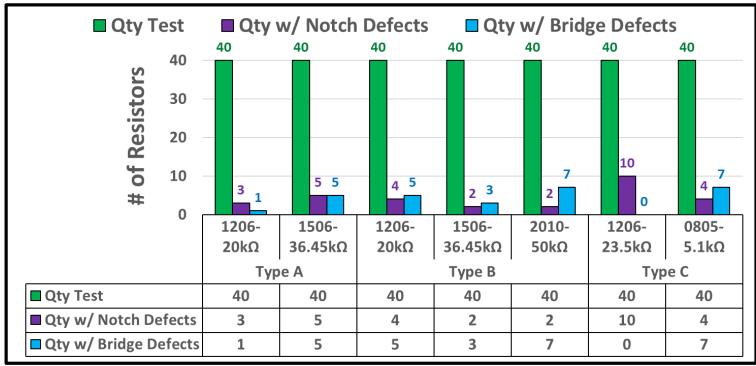
Foil Resistors Used for Evaluation						
Resistor Size	Resistance (Ω)	Power		Resistor Patter	n Geometry	
(EIA Footprint)	& Tolerance	Rating (mW)	Qty	Foil Thickness (µm)	Foil Gridline Width (µm)	* Type
0805	5.1k ± 0.05%	100	40	2.3	6.6	С
1206	20k ± 0.05%	150	40	2.5	4.8	Α
1206	20k ± 0.05%	150	40	2.5	4.8	В
1206	23.5k ± 0.05%	150	40	2.3	4.3	С
1506	36.45k ± 0.05%	200	40	2.8	4.1	Α
1506	36.45k ± 0.05%	200	40	2.8	4.1	В
2010	50k ± 0.01%	300	40	2.5	4.8	В
		Total	280			

*Туре	Foil Classification	Pre-Encapsulation Screen	Powered Screening
Α	Contains Some "Embedded Particles"	100% Visual Inspection	1x Short Time Overload (STOL)
В	"Particle-Free"	100% Visual Inspection	1x Short Time Overload (STOL)
С	"Particle-Free"	100% Visual Inspection	2x Short Time Overload (STOL)

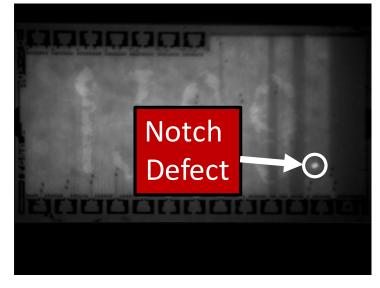
Results: Pre-Life Test Pulsed-Power Infrared Screening

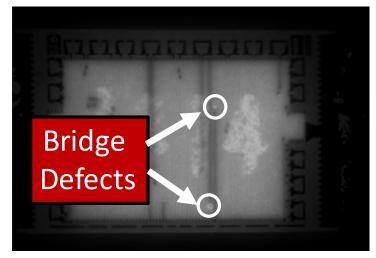






- quy my motern beneats	•	
■ Qty w/ Bridge Defects	1	
Totals		
280 Tested		
30 with Notch D	efects	
28 with Bridge Defects		

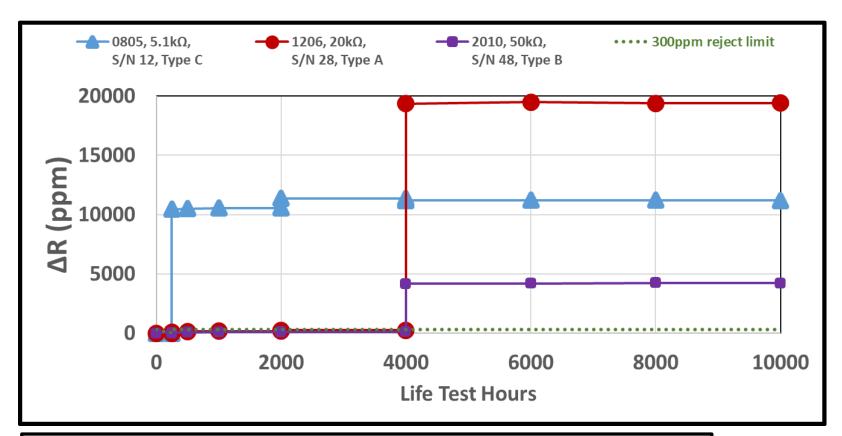


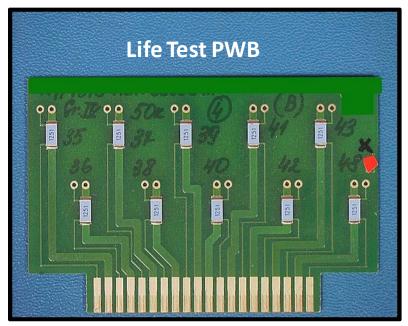


Results: 3 Life Test Failures (280 Resistors Tested)

NASA

Abrupt Positive Resistance Shift Failure Modes

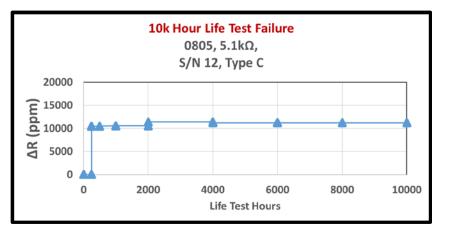




* S/N 12 exhibits 2 distinct positive shifts during life test

Failure Analysis:

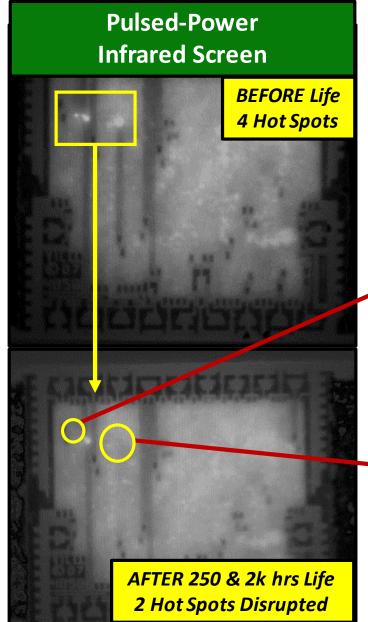
0805, 5.1kΩ, S/N12, Type "C"



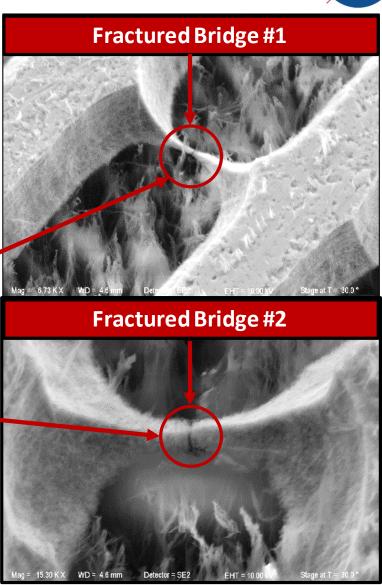
Conclusion:

Two bridge defects fractured during life test causing total ΔR ~11000 ppm

Pulsed-Power Infrared Screen detected both bridge defects as 'hot spots' BEFORE Life Test

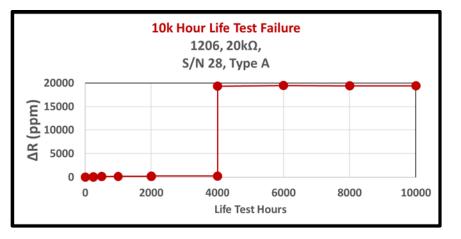






Failure Analysis:

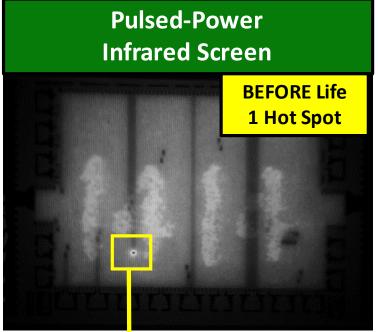
1206, 20kΩ, S/N 28, Type "A"

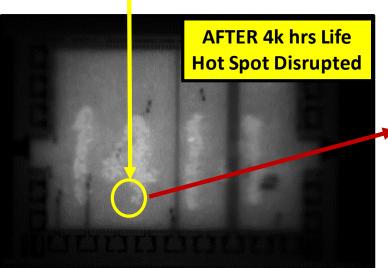


Conclusion:

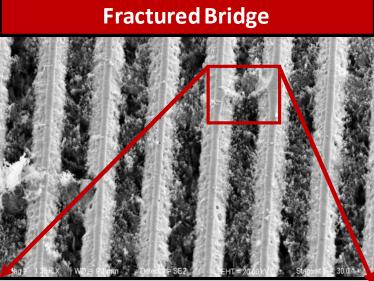
One bridge defect fractured during life test causing ΔR ~19400 ppm

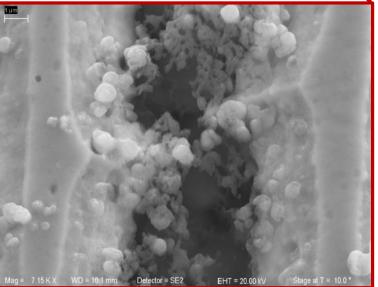
Pulsed-Power Infrared Screen detected this bridge defect as a 'hot spot' BEFORE Life Test





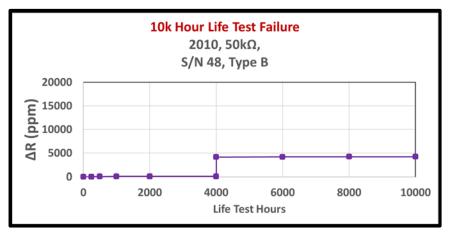






Failure Analysis:

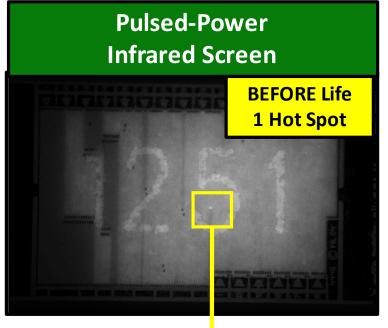
2010, 50kΩ, S/N48, Type "B"

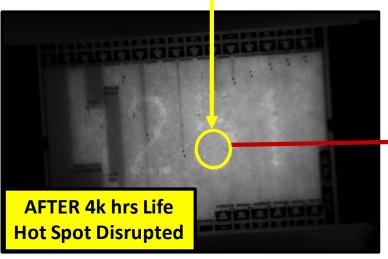


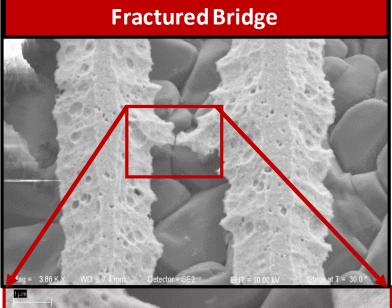
Conclusion:

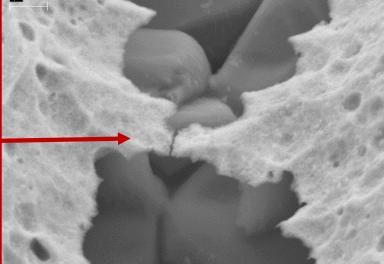
One bridge defect fractured during life test causing ΔR ~4200 ppm

Pulsed-Power Infrared Screen detected this bridge defect as a 'hot spot' BEFORE Life Test









Conclusions



- L. Standard screening techniques (e.g., pre-encapsulation visual, STOL, DPA)
 Do NOT detect all resistors with significant constriction defects in the resistor pattern.
- 2. Resistor failures (i.e., positive ΔR and open circuit) sometimes occur due to thermomechanically-induced fatigue fracture of localized constriction defects in the resistor pattern (e.g., notches, bridges, embedded particles).
- 3. New Pulsed-Power Infrared Screening technique has been developed
 - Detects localized constriction defects as "hot spots" using high resolution infrared thermography
 - Proven effective via 10k hour life test with failure analyses correlating pre-existing constriction defects to 'hot spots' and subsequent fractured constrictions after life test
 - Suitable for use as an 'In-Process Manufacturer Screening Inspection' prior to encapsulation And as a non-destructive 'Post-Procurement' screen for SMT foil resistors

New Screening Technique Can Take a Super Stable Resistor Technology and Make it Super Reliable Too





NASA Electronic Parts & Packaging (NEPP) Program			
Mike Sampson	Dr. Henning Leidecker		
Manager,	Chief Parts Engineer,		
NASA Electronic Parts & Packaging Program	NASA Goddard Space Flight Center		

NASA Goddard Space Flight Center Office of Safety and Mission Assurance

Jack Shue

Alexandros Bontzos, Chris Greenwell,
Tim Mondy, Nilesh Shah,
Ron Weachock
NASA Goddard Space Flight Center
Parts Analysis Laboratory

Foil Resistor Samples and Life Testing Services Provided by

Vishay Precision Group (VPG)



Backup Slides

High Resolution Infrared Camera with 4x lens option *FLIR SC8200, SC8300 Series*

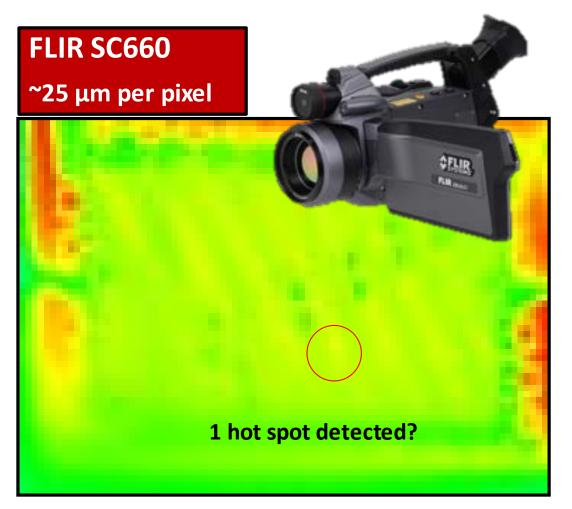


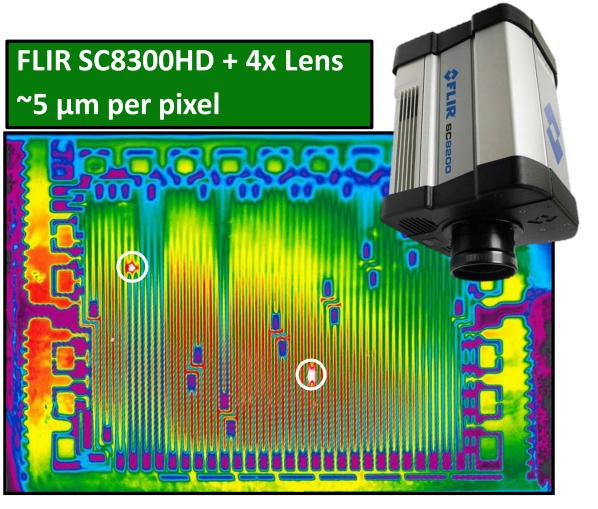


Parameter	Specification
Detector	InSb
Spectral Range	3 μm to 5 μm
Measurement	-20°C to +350°C
Temperature Range	
Field of View	~4.6mm x 5.6mm (> 1 million pixels)
Resolution	~ 5 μm per pixel
Focal Working Distance	~25mm
Frame Capture Rate	>100 frames per second (fps)

Comparison of Two Different Infrared Cameras

Inspecting the same resistor with 2 constriction defects while applying power pulses



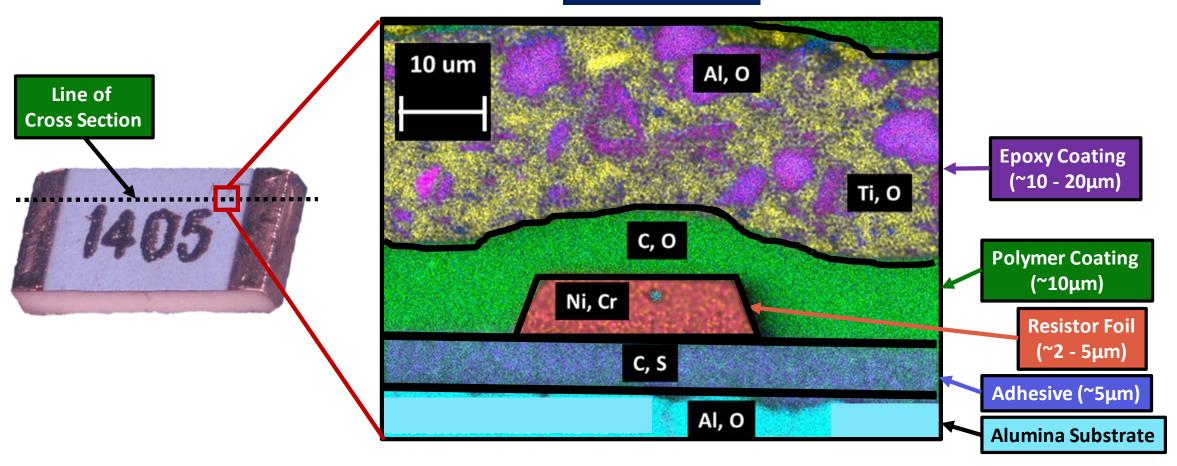




Basic Construction of a SMT Foil Resistor

Cross Section



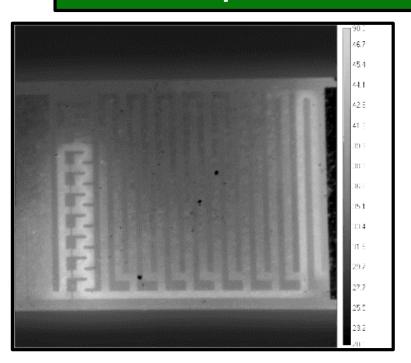


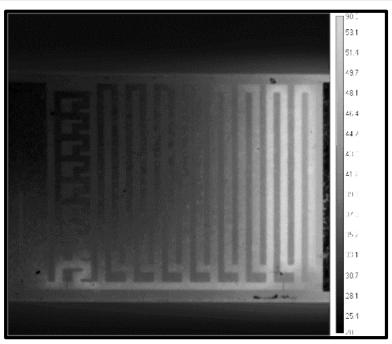


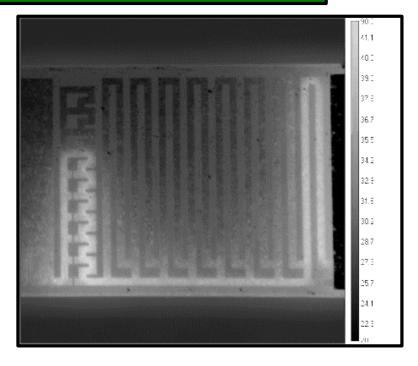


Applying 6.25x Rated Power for 100 ms pulses; 10% duty cycle

Infrared Inspection Performed Without Removing Resistor Protective Coatings



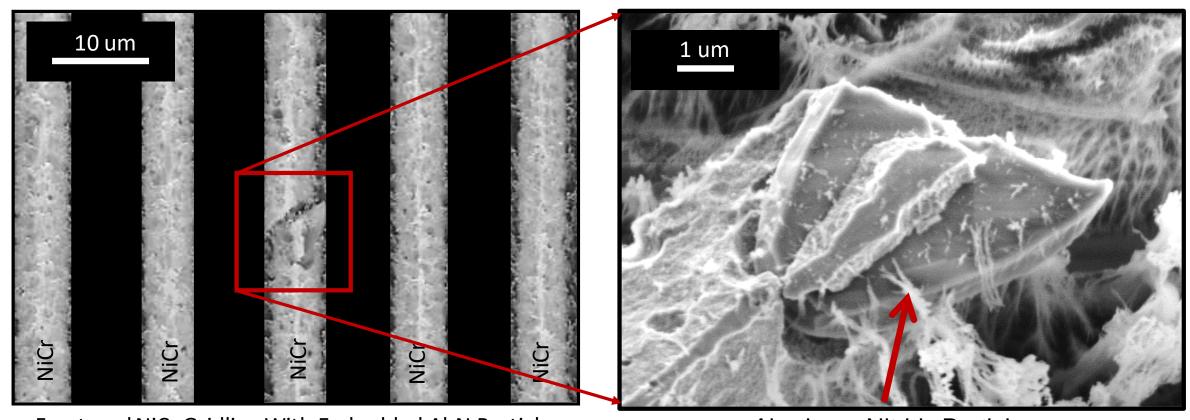






A Case for an Improved Screening Method:

Embedded Al-N Particle in Foil Resistor Size 1206, 30 k Ω



Fractured NiCr Gridline With Embedded Al-N Particle

Aluminum Nitride Particle

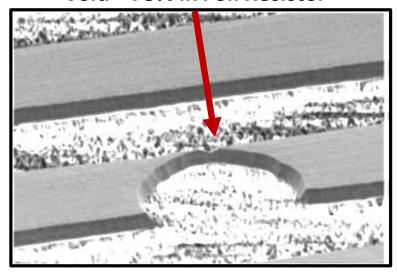
Traditional Resistor Screening Methods



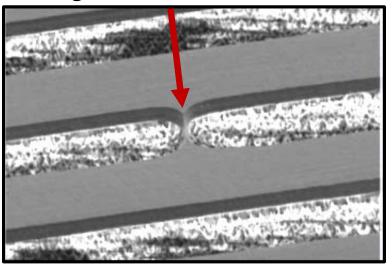
Optical Microscopy

	Thin Film (MIL-PRF-55342)	Foil Resistors
Test Conditions	30x to 60x optical microso	copy prior to encapsulation
Sample Size	100% in-process screen	100% high reliability products only
Rejection Criteria	Voids > 50% nominal line width Bridges < 50% smallest line width	Voids > 75% nominal line width Bridges < 10% smallest line width

Void > 75% in Foil Resistor



Bridge < 10% in Foil Resistor





Traditional Resistor Screening Methods Short Time Overload (STOL)

	Thin Film (MIL-PRF-55342)	Foil Resistors
Test Conditions	6.25x rated	power for 5 seconds
Sample Size	20 pcs (space level only)	10 pcs (high reliability products)
Rejection Criteria	$\Delta R > 0.1\%$	$\Delta R > 0.02\%$

STOL may sometimes force failure of devices with the most severe pattern constrictions



Traditional Resistor Screening Methods *Power Conditioning*

	Thin Film (MIL-PRF-55342)	Foil Resistors
Test Conditions	1.5x rated power for 100 hours at 70°C	
Sample Size	100% (space level only)	100% (high reliability products only)
Rejection Criteria	$\Delta R > 0.2\%$	$\Delta R > 0.03\%$

Power Conditioning may sometimes force failure of devices with the most severe pattern constrictions